



### 60V N-Channel Enhancement Mode MOSFET

Voltage

60 V

Current

18 A

#### **Features**

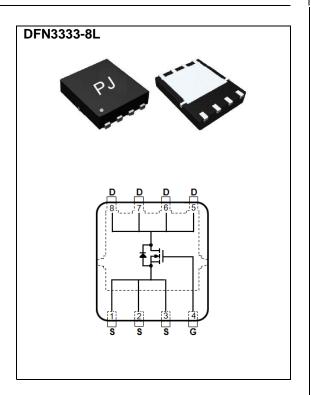
- $R_{DS(ON)}$ ,  $V_{GS}@10V$ ,  $I_D@10A<34m\Omega$
- $R_{DS(ON)}$ ,  $V_{GS}@4.5V$ ,  $I_D@5A<40m\Omega$
- High switching speed
- Improved dv/dt capability
- Low reverse transfer capacitance
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

#### **Mechanical Data**

• Case: DFN3333-8L Package

• Terminals : Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 0.001 ounces, 0.03 grams



# **Maximum Ratings and Thermal Characteristics** (T<sub>A</sub>=25 °C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V <sub>DS</sub>	60		
Gate-Source Voltage		$V_{GS}$	<u>+</u> 20	V	
Continuous Drain Current (Note 4)	T <sub>C</sub> =25°C	I <sub>D</sub>	18		
	T <sub>C</sub> =100°C		12	А	
Pulsed Drain Current (Note 1)	T <sub>C</sub> =25°C	I <sub>DM</sub>	72		
Power Dissipation	T <sub>C</sub> =25°C	Po	23.8	W	
	T <sub>C</sub> =100°C		11.9		
Continuous Drain Current t (Note 4)	T <sub>A</sub> =25°C	I <sub>D</sub>	5	_	
	T <sub>A</sub> =70°C		4	A	
Power Dissipation	T <sub>A</sub> =25°C	Po	2.4	10/	
	T <sub>A</sub> =70°C		1.6	W	
Single Pulse Avalanche Energy (Note 6)		E <sub>AS</sub>	24	mJ	
Operating Junction and Storage Temperature Range		$T_{J}$ , $T_{STG}$	-55~175	°C	
Typical Thermal Resistance (Note 4,5)	Junction to Case	$R_{ heta JC}$	6.3	°C/W	
	Junction to Ambient	$R_{\theta JA}$	62.5		

Limited only By Maximum Junction Temperature





### **Electrical Characteristics** (T<sub>A</sub>=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS		
Static								
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =250uA	60	-	-	V		
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ , $I_{D}=250uA$	1	1.83	2.5			
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =10A	-	28	34	mΩ		
		$V_{GS}$ =4.5V, $I_{D}$ =5A	-	33	40			
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =60V, V <sub>GS</sub> =0V	-	-	1	uA		
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> = <u>+</u> 20V, V <sub>DS</sub> =0V	-	-	<u>+</u> 100	nA		
Dynamic (Note 7)								
Total Gate Charge	$Q_g$	V <sub>DS</sub> =30V, I <sub>D</sub> =10A, V <sub>GS</sub> =10V <sup>(Note 1,2)</sup>	-	20	-	nC		
Gate-Source Charge	$Q_gs$		-	3.8	-			
Gate-Drain Charge	$Q_gd$	V <sub>GS</sub> =10V	-	3.9	-			
Input Capacitance	Ciss		-	1173	-	pF		
Output Capacitance	Coss	$V_{DS}$ =25V, $V_{GS}$ =0V, f=1MHZ	-	63	-			
Reverse Transfer Capacitance	Crss	I=IIVIAZ	-	44	-			
Turn-On Delay Time	td <sub>(on)</sub>	\/ 45\/   40	-	7.1	-			
Turn-On Rise Time	t <sub>r</sub>	V <sub>DD</sub> =15V, I <sub>D</sub> =1A,	-	25	-	ns		
Turn-Off Delay Time	td <sub>(off)</sub>	$V_{GS}=10V, R_{G}=6\Omega$ (Note 1,2)	-	31	-			
Turn-Off Fall Time	t <sub>f</sub>		-	20	-			
Drain-Source Diode								
Maximum Continuous Drain-Source			-	-	17	А		
Diode Forward Current	I <sub>S</sub>							
Reverse Recovery Time	$V_{SD}$	I <sub>S</sub> =1A, V <sub>GS</sub> =0V	-	0.72	1	V		

#### NOTES:

- 1. Pulse width<a>300us</a>, Duty cycle<a>2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Repetitive rating, pulse width limited by junction temperature T<sub>J(MAX)</sub>=150°C. Ratings are based on low frequency and duty cycles to keep initial T<sub>J</sub> =25°C.
- 4. The maximum current rating is package limited.
- 5. R<sub>OJA</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch<sup>2</sup> with 2oz.square pad of copper.
- 6. The test condition is L=0.1mH, I<sub>AS</sub>=22A, V<sub>DD</sub>=25V, V<sub>GS</sub>=10V, Starting T<sub>J</sub>=25°C.
- 7. Guaranteed by design, not subject to production testing.





### TYPICAL CHARACTERISTIC CURVES

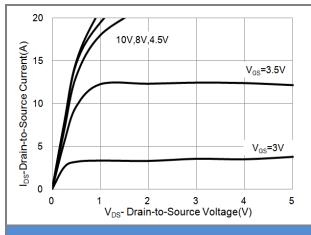
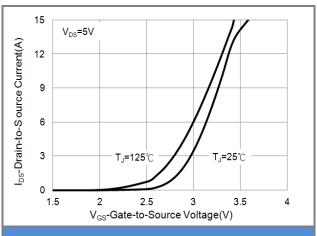


Fig.1 On-Region Characteristics



**Fig.2 Transfer Characteristics** 

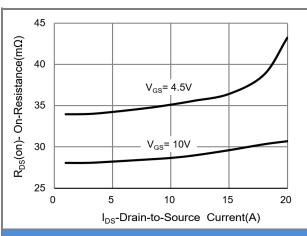


Fig.3 On-Resistance vs. Drain Current

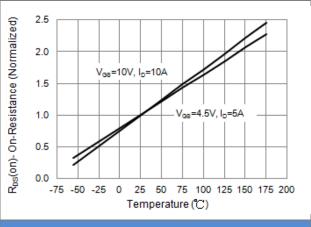


Fig.4 On-Resistance vs. Junction temperature

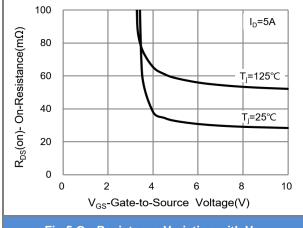


Fig.5 On-Resistance Variation with V<sub>GS</sub>

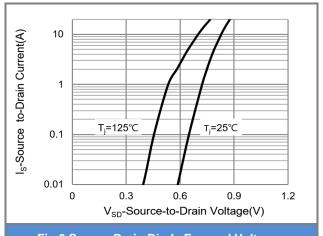


Fig.6 Source-Drain Diode Forward Voltage





#### TYPICAL CHARACTERISTIC CURVES

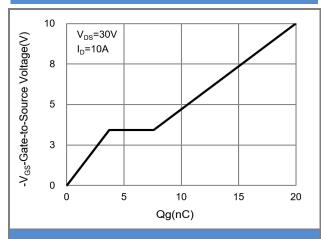


Fig.7 Gate-Charge Characteristics

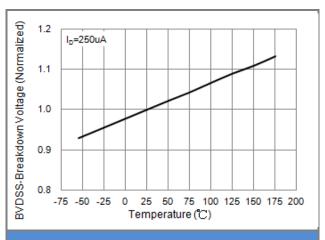


Fig.8 Breakdown Voltage Variation vs. Temperature

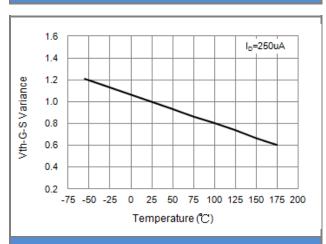


Fig.9 Threshold Voltage Variation with Temperature

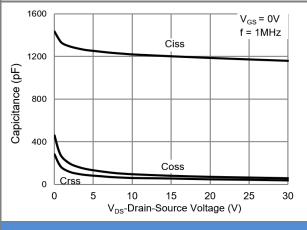
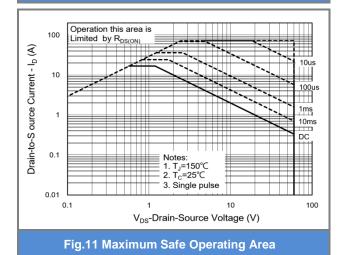


Fig.10 Capacitance vs. Drain-Source Voltage



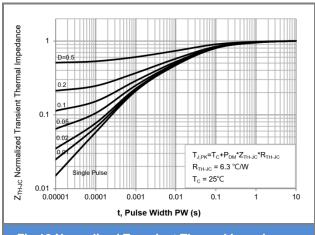


Fig.12 Normalized Transient Thermal Impedance

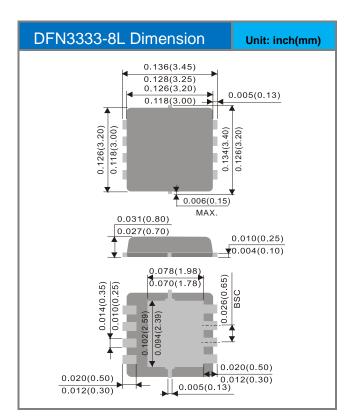


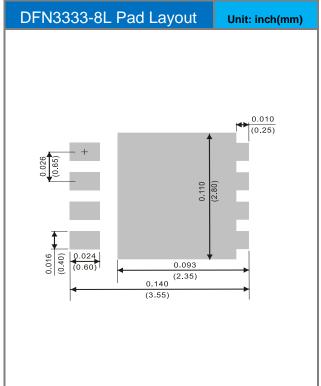


### **Part No Packing Code Version**

Part No Packing Code	Package Type	Packing Type	Marking	Version
PJQ4468AP-AU_R2_000A1	DFN3333-8L	5K pcs / 13" reel	4468	Halogen free

### **Packaging Information & Mounting Pad Layout**









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